

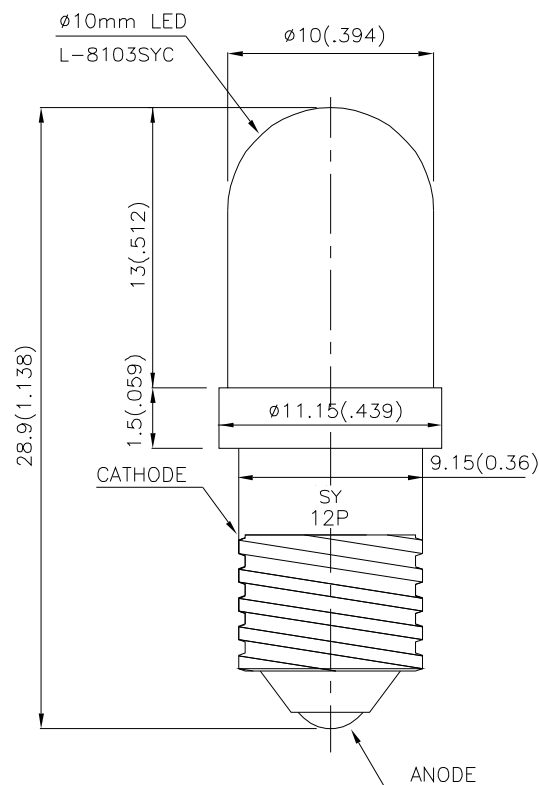
Features

- BUILT-IN CURRENT LIMITING RESISTOR FOR DIRECT APPLICATION OF DIFFERENT ACROSS CURRENT.
- LONG LIFE.
- LOW CURRENT, POWER SAVINGS.
- LOW MAINTENANCE.
- DIFFERENT COLOR AVAILABLE.
- SOLID STATE, HIGH VIBRATION RESISTANT.
- 12V INTERNAL RESISTOR.
- RoHS COMPLIANT.

Description

The Super Bright Yellow device is made with DH InGaAlP (on GaAs substrate) light emitting diode chip.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
3. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) V=12V		Viewing Angle
			Min.	Typ.	2θ1/2
BLS101SYC-12V-P	SUPER BRIGHT YELLOW (InGaAlP)	WATER CLEAR	480	1200	20°

Note:

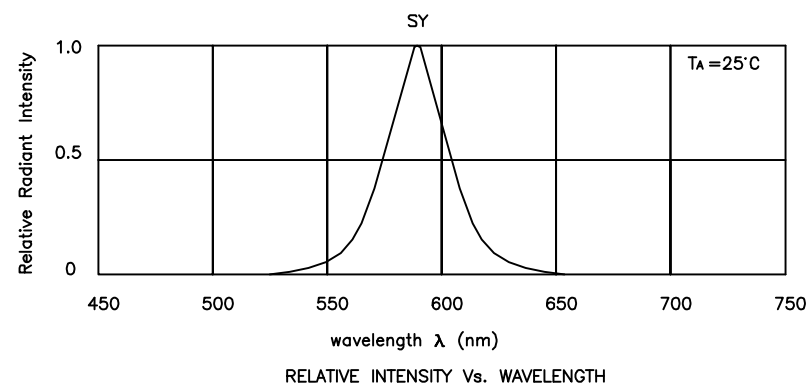
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Super Bright Yellow	590		nm	V _F =12V
λ_D	Dominant Wavelength	Super Bright Yellow	588		nm	V _F =12V
$\Delta\lambda_{1/2}$	Spectral Line Half-width	Super Bright Yellow	28		nm	V _F =12V
I _F	Forward Current	Super Bright Yellow	26	30	mA	V _F =12V
I _R	Reverse Current	Super Bright Yellow		10	uA	V _R = 5V

Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Yellow	Units
Power dissipation	400	mW
Forward Voltage	14	V
Reverse Voltage	5	V
Operating Temperature	-40°C To +70°C	
Storage Temperature	-40°C To +85°C	



Super Bright Yellow

BLS101SYC-12V-P

